

SGM4703 High-Power Stereo Class-D Audio Power Amplifier with Adjustable Power Limit and Automatic Level Control

SGM4703 GENERAL DESCRIPTION

The SGM4703 is a high-power, high-efficiency, stereo Class-D audio power amplifier with adjustable power limit (APL) and automatic level control (ALC). It operates with a wide range of supply voltages from 5V to 26V. With 24V supply voltage, it can deliver $2 \times 40W$ peak output power for a pair of 8 Ω speakers with 10% THD+N.

The high efficiency of SGM4703 extends battery life in playing music and allows it to deliver an output power of $2 \times 20W$ without the need for a bulky heat sink on a two-layer system board. Its high PSRR and low EMI emission reduce system design and manufacturing complexities, as well as lower system cost.

The SGM4703 features APL and ALC. The APL limits peak audio outputs to a user-defined value to protect audio speakers from excessive power dissipation or over-load. The APL and ALC adjust the voltage gain of the audio amplifiers in response to over-limit audio inputs, eliminating output clipping distortion while maintaining a maximally allowed dynamic range of audio outputs. The limiting voltage of APL and ALC can be either a user-defined value or the supply voltage.

The SGM4703 can be configured into driving either a pair of speakers in Bridge-Tied-Load (BTL) configuration for stereo applications or a single speaker in Parallel BTL (PBTL) configuration for mono applications.

The SGM4703 features two PWM modulation schemes for Class-D audio amplifiers: Dual-Side-Modulation (DSM) and Single-Side-Modulation (SSM).

In SGM4703, comprehensive protection modes against various operating faults ensure its safe and reliable operation.

SGM4703 FEATURES

- Wide Range of Supply Voltages from 5V to 26V
- Adjustable Power Limit to Safeguard Audio Speakers
- Automatic Level Control to Eliminate Output Clipping
- Four Selectable Gain Settings: 20/26/30/34dB
- Three Selectable ALC Dynamic Characteristics
- Two Selectable PWM Frequencies with Optional Spread-Spectrum: 360kHz and 500kHz
- Two Selectable Modulation Schemes: SSM and DSM
- Optional PBTL Configuration for Mono Applications
- Peak Output Power in Non-ALC
 - + 2 × 40W (V_{DD} = 24V, 8 Ω + 33 μ H, BTL, THD+N = 10%)
 - + 2 × 32W (V_{DD} = 24V, 8 Ω + 33 μ H, BTL, THD+N = 1%)
 - + 80W (V_{DD} = 24V, 4 Ω + 33 μ H, PBTL, THD+N = 10%)
 - 64W (V_{DD} = 24V, 4 Ω + 33µH, PBTL, THD+N = 1%)
- ALC Output Power (THD+N < 0.5%) in ALC
 - + 2 × 30W (V_{DD} = 24V, 8Ω + 33μH, BTL)
 - + 2 × 21W (V_{DD} = 15V, 4Ω + 33μH, BTL)
 - 60W (V_{DD} = 24V, 4Ω + 33µH, PBTL)
- Wide ALC Dynamic Range: 12dB (V_{DD} = 12V)
- Low THD+N: 0.02% (V_{DD} = 24V, 8Ω + 33µH, P₀ = 20W/Ch)
- High PSRR: 80dB at 1kHz with SSM
- Protection Modes against Various Operating Faults Including Under-Voltage, Over-Voltage, Over-Current, Over-Temperature, and DC-Detect
- Available in a Green TSSOP-28 (Exposed Pad) Package

SGM4703 APPLICATIONS

Bluetooth/Wireless Speakers Consumer Audio Speakers Soundbars



SGM4703 PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM4703	TSSOP-28 (Exposed Pad)	-40°C to +85°C	SGM4703YPTS28G/TR	SGM4703 YPTS28 XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

XXXXX

- Vendor Code
- Trace Code
 - —— Date Code Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage Pins	
AVDD, PVDD	0.3V to 30V
Digital I/O Pins	
EN, FAULTB	0.3V to V _{AVDD} + 0.3V
MODS	0.3V to V _{GVDD} + 0.3V
Analog Output Pins	
GVDD	0.3V to 6.5V
ALC, GAIN, FREQ	0.3V to V _{GVDD} + 0.3V
Analog Input Pins	
INPL/R, INNL/R, PLIMIT	0.3V to V _{GVDD} + 0.3V
Package Thermal Resistance	
TSSOP-28 (Exposed Pad), θ _{JA}	
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s).	+260°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



SGM4703 RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Supply Voltage Range (1, 2)	V _{DD}	PVDD, AVDD	5		26	V	
Operating Ambient Temperature	T _A		-40		85	°C	
Digital Input Valtage at EN	M	Logic Low			0.8	V	
Digital input voltage at EN	VEN	Logic High	2		VAVDD	v	
Digital Input Valtage at MODS	V	Logic Low			0.8	V	
Digital liput voltage at NODS	V MODS	Logic High	2		V_{GVDD}	v	
Minimum I oad Impedance ⁽³⁾	P.	BTL Configuration (Stereo)	3.2	4		0	
Minimum Load impedance	NL.	PBTL Configuration (Mono)	2	3	<u>^</u>	12	
Audio Input Capacitor	CIN	At INPL/R, INNL/R	0.1	1	2.2	μF	
External Audio Input Resistor	R _{INE}	At INPL/R, INNL/R	0		20	kΩ	
Maximum Audio Input Voltage Level	$V_{\text{IN, MAX}}$	At INNL/R, INPL/R			2.0	V_{RMS}	
PLIMIT Voltage Range	V _{PLIMIT}	PLIMIT	0		V _{GVDD}	V	
Maximum Load Current at GVDD	ILOAD				5	mA	
	Caura	Ceramic	0.1	1			
Supply Decoupling Capacitor	OPVDD	Electrolytic or Tantalum ⁽⁴⁾	100	220			
	C_{AVDD}	Ceramic		1		μF	
	C_{GVDD}	Ceramic		1			
	CPLIMIT	Ceramic		0.1			
Bootstrap Holding Capacitor	C _B	At BSTPL/R, BSTNL/R	0.068	0.1	0.22	μF	
Mono Mode Select	INNR INPR	PBTL Configuration	В	oth Pins Sh	orted to GN	D	
Modulation Scheme Select	MODS	Single-Side-Modulation (SSM)		High o	r Open		
	WODS	Double-Side-Modulation (DSM)		Lo	W		
		26dB		Op	en		
Voltago Gain Soloct	GAIN	30dB		Shorted	to GND		
Voltage Gain Gelect	OAIN	34dB		68kΩ t	o GND		
		20dB		300kΩ	to GND		
		Non-ALC		Op	en		
ALC Mada Salaat		ALC-1		Shorted	to GND		
ALC WIDDE Select	ALC	ALC-2		68kΩ t	o GND		
		ALC-3		300kΩ	to GND		
		Constant Frequency at 360kHz		Ор	en		
DW/M Eroquoney Soloct	EPEO	360kHz with Spread-Spectrum	Shorted to GND				
	TREQ	Constant Frequency at 500kHz		68kΩ t	o GND		
		500kHz with Spread-Spectrum	300kΩ to GND				

NOTES:

1. The peak supply voltage including its tolerance over various operating conditions must not exceed its absolute-maximum-rated value (26V). Exposure to absolute-maximum-rated supply voltage may damage the device or affect device reliability permantly.

2. For high power applications, the maximum power supply V_{DD} that can be applied to the SGM4703 is largely limited by the thermal dissipation capability of the package and the system board layout.

3. The SGM4703 is specfied with an 8Ω resistive load in series with 33μ H inductive load or with a 4Ω resistive load in series with 33μ H inductive load or with a 2Ω or 3Ω resistive load in series with 15μ H inductive load (in PBTL configuration). Without inductive loads, the maximum continous output power will severely suffer from efficiency and thermal degradation.

4. If the input supply is located more than a few centimeters from SGM4703, additional bulk capacitor may be required in addition to the ceramic capacitors.



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SGM4703 PIN CONFIGURATION



SGM4703 PIN DESCRIPTION

PIN	NAME	TYPE	DESCRIPTION
1	EN	DI	Chip enable (active high) with an on-chip $250k\Omega$ pull-down resistor to ground. A TTL logic input in compliance with AVDD.
2	FAULTB	DO	Open-drain output indicating operational faults of OCP or DCP. Both faults can be set for auto-recovery by externally connecting FAULTB to EN. Otherwise, both OCP and DCP faults must be reset by cycling EN. A TTL logic output in compliance with AVDD.
3	INPL	AI	Left-channel non-inverting audio input biased at one half of GVDD.
4	INNL	AI	Left-channel inverting audio input biased at one half of GVDD.
5	GAIN	AO	Voltage gain select with an on-chip $250k\Omega$ pull-down resistor to ground. Connect to a resistor to ground to set the voltage gain of the audio amplifiers.
6	FREQ	AO	PWM frequency select with an on-chip $250k\Omega$ pull-down resistor to ground. Connect to a resistor to ground to set the PWM frequency with optional spread-spectrum.
7	AVDD	Р	Analog supply. Connect to a 1μ F capacitor for decoupling. Also, add a decoupling resistor of 10Ω between this pin and the system power supply for high-frequency filtering.
8	AGND	G	Analog ground. Connect to the system power ground GND.
9	GVDD	AO	Internally generated reference voltage at 5.6V. Connect to a 1µF capacitor for decoupling.
10	PLIMIT	AI	Adjustable power-limit. Connect to a resistor divider from GVDD to AGND to set the output voltage limit. Add a 0.1µF capacitor for decoupling.
11	INNR	AI	Right-channel inverting audio input biased at one half of GVDD. Connect to ground (without decoupling capacitor) for mono mode in PBTL configuration.
12	INPR	AI	Right-channel non-inverting audio input biased at one half of GVDD. Connect to ground (without decoupling capacitor) for mono mode in PBTL configuration.
13	ALC	AO	ALC mode select with an on-chip $250k\Omega$ pull-down resistor to ground. Connect to a resistor to ground or leave open to set ALC dynamic characteristic.



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SGM4703 PIN DESCRIPTION (continued)

PIN	NAME	TYPE	DESCRIPTION
14	MODS	DI	PWM modulation select with an on-chip 250k Ω pull-up resistor to GVDD. A TTL logic input in compliance with GVDD.
15, 16	PVDD	Р	Power supply inputs for the right-channel H-bridge. The power supplies for right-channel and left-channel H-bridges are internally.
17	BSTPR	AO	Connect to bootstrap holding capacitor for the right-channel non-inverting audio output, VOPR. A 0.1µF capacitor must be placed between this pin and VOPR for proper operation.
18	VOPR	AO	Right-channel non-inverting audio output terminal.
19	PGND	G	Power ground for the right-channel H-bridge. Connect to the system ground GND. The power ground for right-channel and left-channel H-bridges are internally shorted.
20	VONR	AO	Right-channel inverting audio output terminal.
21	BSTNR	AO	Connect to a bootstrap holding capacitor for the right-channel inverting audio output, VONR. A 0.1µF capacitor must be placed between this pin and VONR for proper operation.
22	BSTNL	AO	Connect to a bootstrap holding capacitor for the left-channel inverting output, VONL. A 0.1µF capacitor must be placed between this pin and VONL for proper operation.
23	VONL	AO	Left-channel inverting audio output terminal.
24	PGND	G	Power ground for the left-channel H-bridge. Connect to the system ground GND. The power ground for right-channel and left-channel H-bridges are internally shorted.
25	VOPL	AO	Left-channel non-inverting audio output terminal.
26	BSTPL	AO	Connect to a bootstrap holding capacitor for the left-channel non-inverting output, VOPL. A 0.1µF capacitor must be placed between this pin and VOPL for proper operation.
27, 28	PVDD	Р	Power supply inputs for the left-channel H-bridge. The power supplies for right-channel and left-channel H-bridges are internally shorted.
Exposed Pad	GND	G	Exposed pad. Connect to the system ground GND.

SGM4703 TYPICAL APPLICATION







SGM4703 IMPORTANT APPLICATION NOTES

Output Power Considerations

1. The maximum output power of SGM4703 is determined primarily by the power supply (its output voltage and current) and speaker impedance. As a high power audio amplifier, the maximum output power of SGM4703 can be severely limited by the thermal dissipation capability of the system board layout.

2. The SGM4703 is packaged with an exposed thermal pad on the underside of the device. Solder the thermal pad directly onto a large grounded metal island (GND) underneath the package, as a thermal sink for proper thermal dissipation. On the grounded metal island, place several rows of solid, equally-spaced vias connecting to the bottom layer of the system board. Failure to do so can severely limit its thermal dissipation capability. It might even cause the device going into over-temperature shutdown occasionally.

3. Use wide open areas around the SGM4703 on the top and bottom layers of the system board as the ground plane GND. Place lots of solid vias connecting the top and bottom layers of GND. Furthermore, for proper thermal dissipation, reserve wide and uninterrupted GND areas along the thermal flow on the top layer, i.e., no wires cutting through the GND layer and obstructing the thermal flow in the proximity of the device.

4. All the power ground pins PGND are directly shorted to the ground plane GND as a central "star" ground for the SGM4703. Use a single point of connection between the analog ground AGND and the ground plane GND to minimize the coupling of high-current switching noise onto audio signals.

5. The power supply pins, PVDD, for the audio amplifiers' output stages are directly connected together with short and wide metal traces.

6. Use direct and low-impedance traces from the audio outputs (VOPL/R and VONL/R) to their individual output filters and speakers.

Output Filter Considerations

7. For most applications, the SGM4703 does not require an LC output filter when speaker wires are less than 10cm.

8. A ferrite bead filter constructed from a ferrite bead and a ceramic capacitor can be used to suppress EMI. Choose a ferrite bead with a rated current no less than 4A for 8Ω loads, 7A for 4Ω loads, and 9A for 3Ω or less loads (in PBTL configuration). Place the filter tightly together and as close as possible to the audio amplifier's output pins. A ferrite bead filter can also reduce high-frequency interference.

9. For applications where EMC requirements are extremely stringent or speaker wires are long, use a second-order LC lowpass filter. Place the filter tightly together and as close as possible to the audio amplifier's output pins. The LC output filter must be designed specifically for the speaker load since the load impedance affects the quality factor of the filter.

General Considerations

10. The SGM4703 requires adequate power supply decoupling to ensure its peak output power, high efficiency, low distortion, and low EMI emissions. Place each supply decoupling capacitor as individually close as possible to AVDD and PVDD pins.

11. Place a small decoupling resistor (10 Ω) between the system power supply and AVDD to prevent high frequency Class-D transient spikes from interfering with the on-chip linear amplifiers.

12. For best noise performance, use differential inputs from the audio source for SGM4703. In single-ended input applications, the unused inputs of SGM4703 must be AC-grounded at the audio source. Also, take care to match the impedances seen at two differential inputs closely.

13. The maximum input signal dictates the required voltage gain to achieve the desired maximum output power. For best noise performance, consider a voltage gain as low as possible.

14. Do not alter the logic state of the MODS pin while the device is in operation. To change the setting of the pin, the device must be first brought into shutdown mode by pulling the EN pin low for at least 10ms before it can be restored to its normal operation.



SGM4703 TEST SETUP FOR ELECTRICAL AND PERFORMANCE CHARACTERISTICS



Figure 2. Test Setup Diagram

All parameters specified in Electrical and Typical Performance Characteristics sections are measured according to the conditions:

1. The two differential inputs are shorted for common-mode input voltage measurement. All other parameters are taken with input resistors $R_{INE} = 0k\Omega$ and input capacitors $C_{IN} = 1\mu$ F, unless otherwise specified.

2. The supply decoupling capacitors $C_S = 2 \times (10nF + 1\mu F + 220\mu F)$ are placed close to the device.

3. A 33µH inductor was placed in series with the load resistor to emulate a speaker load for all AC and dynamic parameters.

4. The 33kHz lowpass filter is added even if the analyzer has an internal lowpass filter. An RC lowpass filter (1k Ω , 4.7nF) is used on each output for the data sheet graphs.



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SGM4703 ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL		CONDITIONS		TYP	MAX	UNITS		
Supply Voltage	V _{DD}	PVDD, AVDD		5		26	V		
Supply Quiescent Current	I _{VDD}	Inputs AC-gro	ounded, No Load		15		mA		
Mute Current	I _{MUTE}	PLIMIT = GNI	D, No Load		8		mA		
Chutdown Current	1		SSM		36				
Shuldown Current	I _{SD}	EN = UV	DSM		58		μΑ		
Supply Voltage UVLO Detection	VUVLOUP	V _{DD} Rising		K A	4.6		V		
Supply Voltage UVLO Release	V _{UVLODN}	V_{DD} Falling			4.3		V		
Supply Voltage OVP Detection	VOVPUP	V _{DD} Rising			28		V		
Supply Voltage OVP Release	VOVPDN	V _{DD} Rising			26.5		V		
Voltage Regulator Output	V _{GVDD}	No Load			5.6		V		
Input Common-Mode Bias	V _{COMM}	INPL/R, INNL	/R		2.8		V		
Digital "Low" Input Voltage	VIL	EN, MODS		Ť.		0.8	V		
Digital "Ligh" Input Valtage	V	EN	2.0		V _{AVDD}	V			
Digital High Input Voltage	VIH	MODS		2.0		V _{GVDD}	/DD		
Digital "Low" Output Voltage	V _{OL}	FAULTB, R _{PU}	_{LLUP} = 100kΩ, V _{DD} = 18V			0.4	V		
Pull-Down Resistor to Ground	R _{DOWN}	EN, ALC, GA	IN, FREQ		250		kΩ		
Pull-Up Resistor to G _{VDD}	R _{UP}	MODS			250		kΩ		
Output Resistance in Shutdown	R _{OUT-SD}	At VOPL/R, V	'ONL/R, EN = Low		5		kΩ		
	V _{GAIN} Vfreq Valc	Open			2.5				
Voltage Level at		Shorted to GN		0		V			
GAIN, FREQ, ALC Pins		68kΩ to GND		0.55					
		300kΩ to GNI			1.40				
		Open			30				
Internal Input Resistance at	P	R _{GAIN} = 0kΩ		20					
INPL/R, INNL/R Pins	NINI	$R_{GAIN} = 68k\Omega$			12		— κΩ		
		R _{GAIN} = 300kΩ	2		60				
		Open			26				
Voltago Gain	Δ	$R_{GAIN} = 0k\Omega$			30		dB		
Voltage Gall	Av	$R_{GAIN} = 68k\Omega$			34		ЧD		
		R _{GAIN} = 300kΩ	2		20				
	f	Open or R _{FREC}	₂ = 0kΩ		360				
P WW Frequency	ISW	$R_{FREQ} = 68k\Omega$	or R_{FREQ} = 300k Ω		500				
Over Current Limit	1	Dual BTL Cor	nfiguration		8.8		A/Ch		
	LIMIT	PBTL Configu	Iration		13		А		
Over-Temperature Threshold	T _{OTSD}				160		°C		
Over-Temperature Hysteresis	T _{HYS}				20		°C		



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SGM4703 ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = 12V, f = 1kHz, Load = 4\Omega + 33\mu$ H, $C_{IN} = 4 \times 1\mu$ F, $R_{INE} = 4 \times 0\Omega$, GAIN = NC (A_V = 26dB), FREQ = NC (f_{PWN} = 360kHz), MODS = NC (SSM), ALC shorted to GND (ALC-1), $V_{PLIMIT} = V_{GVDD}$, $C_{PVDD} = 2 \times (10$ nF + 1 μ F + 220 μ F), $C_{AVDD} = 1\mu$ F, $C_{GVDD} = 1\mu$ F, $C_B = 4 \times 0.1\mu$ F, both channels driven, $T_A = +25^{\circ}$ C, unless otherwise specified.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Class-D Amplifier (V _{DD} = 12V, R _L =	= 4Ω + 33µH,	Both Channels Driven)					
Maximum Output Power	P _{O, MAX}	THD+N = 1%			15		W/Ch
ALC Output Power	$P_{O,ALC}$	V _{IN} = 0.50V _{RMS}			13		W/Ch
		D = 111//Ch Non ALC Mode	SSM		0.04		
		$F_0 = 100/CH, NOT-ALC Mode$	DSM		0.02		
Total Harmonia Distortion + Naisa		D = 10141/Ch Non AL C Made	SSM	Кл	0.02		0/
	יישחו		DSM		0.02		70
		V _{IN} = 0.50V _{RMS} , ALC Mode	SSM		0.3		
			DSM		0.3		
Dower Efficiency	2	P _o = 10W/Ch, Non-ALC Mode			86		0/
Power Eniciency	()	V _{IN} = 0.50V _{RMS} , ALC Mode			87		70
Output Offset Voltage	Vos	No Load			±20		mV
Idle-Channel Noise	V _N	Inputs AC-Grounded, A-weight	ed		145		μV _{RMS}
Signal-to-Noise Ratio	SNR	Maximum Output (7V _{RMS}), A-we	eighted		94		dB
Dower Supply Dejection Datio		SSM	f = 1kHz		80		٩D
Power Supply Rejection Ratio	PORK	DSM	f = 1kHz		60		uв
Common Mode Rejection Ratio	CMRR	$f = 1$ kHz, $V_{IN} = 0.2V_{RMS}$		60		dB	
Channel Separation	Crosstalk	P _o = 10W, f = 1kHz		85		dB	
	ZY	V _{DD} = 12V		12			
Maximum ALC Attenuation	A _{MAX}	V _{DD} = 15V		10		dB	
		V _{DD} = 18V		8.5			
Startup Time	t STARTUP	Including Fade-In Time			45		ms
Shutdown Settling Time	t _{SD}	Including Fade-Out Time		10			ms
Adjustable Power Limit (APL)							
Mute Mode						0.3	V
APL Mode	V _{PLIMIT}	V_{GVDD} = 5.6V, V_{DD} = 24V, Load	= 4Ω + 33µH	0.7		3.5	V
ALC Mode		$V_{GVDD} = 5.6V$		4.5		V_{GVDD}	V
Output Limit Voltage		V_{PLIMIT} = 1.5V, Load = 4 Ω + 33	μH		9.0		V
DC Current Protection (DCP)							
		V_{DD} = 12V, Load = 4 Ω + 33 μ H			2.4		
DC-Detect Threshold	VDCP	V_{DD} = 15V, Load = 4 Ω + 33 μ H			3.0		V
		V_{DD} = 18V, Load = 4 Ω + 33 μ H		3.6			
Fade-In and Fade-Out							
Fade-In Time	t _{FADEIN}				8		ms
Fade-Out Time	t _{FADEOUT}				5		ms



SGM4703 ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = 15V, f = 1kHz, Load = 4\Omega + 33\mu H, SSM, both channels driven, T_A = +25^{\circ}C, unless otherwise specified.)$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Peak Output Power ⁽¹⁾	P _{O, PEAK}	THD+N = 10%, Non-ALC Mode		27		
		THD+N = 1%, Non-ALC Mode		23		W/CII
ALC Output Power	P _{O, ALC}	$V_{\text{DD}} = 15V, V_{\text{IN}} = 0.60V_{\text{RMS}}$		21		W/Ch
Tatal Llamancia Distantiana I Naisa	THD+N	P _o = 15W/Ch, Non-ALC Mode		0.02		%
		V _{IN} = 0.60V _{RMS} , ALC Mode		0.3		
Dower Efficiency ⁽²⁾	η	P _o = 15W/Ch, Non-ALC Mode		85		%
Power Efficiency		V _{IN} = 0.60V _{RMS} , ALC Mode		86		
Signal-to-Noise Ratio	SNR	P _o = 20W/Ch, A-weighted		95		dB

1	<u> </u>	10\/ f -	1レロラ		o∩ + วว…⊔	COM	hoth char	nolo drivon	T.	- +25°C	unlogo	othonwio	o openified)	ľ
	vdd -	100,1-	INIZ,	Luau – C	52 + 55µ11	, 33101,	Don chai	meis unven,	IA	- +25 C,	uniess	OUTEIWIS	e specilieu.)	1

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Back Output Dower ⁽¹⁾	P _{O, PEAK}	THD+N = 10%, Non-ALC Mode		22			
Feak Oulpul Fower		THD+N = 1%, Non-ALC Mode		18		w/Ch	
ALC Output Power	P _{O, ALC}	V _{IN} = 0.70V _{RMS}		16		W/Ch	
Total Llamania Distantian I Naisa	THD+N	P _o = 10W/Ch, Non-ALC Mode		0.02		0/	
		V _{IN} = 0.70V _{RMS} , ALC Mode		0.3		70	
Dewer Efficiency ⁽²⁾	η	P _o = 10W/Ch, Non-ALC Mode		90		0/	
Power Efficiency		V _{IN} = 0.70V _{RMS} , ALC Mode		91		70	
Signal-to-Noise Ratio	SNR	P _o = 15W/Ch, A-weighted		97		dB	

$(V_{DD} = 24V, f = 1kHz, Load = 8\Omega + 33\mu H, SSM, both channels driven, T_A = +25^{\circ}C, unless otherwise specified.)$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Pook Output Power ⁽¹⁾	P _{O, PEAK}	THD+N = 10%, Non-ALC Mode		40		
Peak Oulput Power		THD+N = 1%, Non-ALC Mode		32		w/Cn
ALC Output Power	P _{O, ALC}	$V_{IN} = 1.0V_{RMS}$		30		W/Ch
Tatal I lama ania Diatationa i Maina	THD+N	P _o = 20W/Ch, Non-ALC Mode		0.02		%
		V _{IN} = 1.0V _{RMS} , ALC Mode		0.3		
Dower Efficiency ⁽²⁾	η	Po = 20W/Ch, Non-ALC Mode		90		%
Power Enciency		V _{IN} =1.0V _{RMS} , ALC Mode		91		
Signal-to-Noise Ratio	SNR	P _o = 25W/Ch, A-weighted		98		dB



SGM4703 ELECTRICAL CHARACTERISTICS (continued)

(V_{DD} = 24V, f = 1kHz, Load = 4Ω + 33µH, SSM, PBTL configuration, T_A = +25°C, unless otherwise specified.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Peak Output Power ⁽¹⁾	P _{O, PEAK}	THD+N = 10%, Non-ALC Mode		80		10/	
		THD+N = 1%, Non-ALC Mode		64		vv	
ALC Output Power	P _{O, ALC}	V _{IN} = 1.0V _{RMS}		60		W	
Tatal Llamania Distantian I Maisa	THD+N	P _o = 40W, Non-ALC Mode		0.1		%	
		V _{IN} = 1.0V _{RMS} , ALC Mode		0.3			
Dower Efficiency ⁽²⁾	η	P _o = 40W, Non-ALC Mode		90		%	
Power Efficiency		V _{IN} = 1.0V _{RMS} , ALC Mode		91			
Signal-to-Noise Ratio	SNR	P _o = 50W, A-weighted		98		dB	

 $(V_{DD} = 15V, f = 1kHz, Load = 3\Omega + 15\mu H, SSM, PBTL configuration, T_A = +25^{\circ}C, unless otherwise specified.)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Book Output Dowor ⁽¹⁾	D	THD+N = 10%, Non-ALC Mode		40		14/
	PO, PEAK	THD+N = 1%, Non-ALC Mode		33		vv
ALC Output Power	P _{O, ALC}	$V_{IN} = 0.60 V_{RMS}$		30		W
Total Harmonic Distortion + Noise	THD+N	P _o = 20W, Non-ALC Mode		0.1		0/
		V _{IN} = 0.60V _{RMS} , ALC Mode		0.3		70
Power Efficiency (2)	η	P _o = 20W, Non-ALC Mode		89		0/
		V _{IN} = 0.60V _{RMS} , ALC Mode		90		70
Signal-to-Noise Ratio	SNR	P _o = 30W, A-weighted		96		dB

$(V_{DD} = 12V, f = 1kHz, Load = 2\Omega + 15\mu H, SSM, PBTL configuration, T_A = +25^{\circ}C, unless otherwise specified.)$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Deak Output Dewar ⁽¹⁾		THD+N = 10%, Non-ALC Mode		37		10/
Peak Output Power	PO, PEAK	THD+N = 1%, Non-ALC Mode		30		vv
ALC Output Power	P _{O, ALC}	$V_{IN} = 0.50 V_{RMS}$		27		W
Total Harmonic Distortion + Noise TH		P _o = 20W, Non-ALC Mode	0.1			0/
	איישח ו	V _{IN} = 0.50V _{RMS} , ALC Mode		0.3		70
Power Efficiency ⁽²⁾	η	P _o = 20W, Non-ALC Mode		87		0/
		V _{IN} = 0.50V _{RMS} , ALC Mode		88		70
Signal-to-Noise Ratio	SNR	P _o = 25W, A-weighted		94		dB

NOTES:

1. The peak output power is defined as an instantaneous maximum output power with no consideration of the thermal dissipation capability of the system board. The maximum continuous output power will be less than the peak output power and largely depend upon the thermal dissipation capability of the system board.

2. All the power efficiency data are given for a two-side, two-layer printed circuit board and shall be used for reference only. The power efficiency will be strongly affected by the thermal dissipation capability of the system board, such as the number of layers and the application of a heat sink.



SGM4703 TYPICAL PERFORMANCE CHARACTERISTICS

 $T_A = +25^{\circ}C$, f = 1kHz, $C_{IN} = 4 \times 1\mu$ F, $A_V = 26$ dB, $f_{PWN} = 360$ kHz, SSM Mode, $V_{PLIMIT} = V_{GVDD}$, both channels driven (BTL Mode), unless otherwise specified.



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 $T_A = +25^{\circ}C$, f = 1kHz, $C_{IN} = 4 \times 1\mu$ F, $A_V = 26$ dB, $f_{PWN} = 360$ kHz, SSM Mode, $V_{PLIMIT} = V_{GVDD}$, both channels driven (BTL Mode), unless otherwise specified.



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 $T_A = +25^{\circ}C$, f = 1kHz, $C_{IN} = 4 \times 1\mu$ F, $A_V = 26$ dB, $f_{PWN} = 360$ kHz, SSM Mode, $V_{PLIMIT} = V_{GVDD}$, both channels driven (BTL Mode), unless otherwise specified.





 $T_A = +25^{\circ}C$, f = 1kHz, $C_{IN} = 4 \times 1\mu$ F, $A_V = 26$ dB, $f_{PWN} = 360$ kHz, SSM Mode, $V_{PLIMIT} = V_{GVDD}$, both channels driven (BTL Mode), unless otherwise specified.



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 $T_A = +25$ °C, f = 1kHz, C_{IN} = 4 × 1µF, A_V = 26dB, f_{PWN} = 360kHz, SSM Mode, V_{PLIMIT} = V_{GVDD}, both channels driven (BTL Mode), unless otherwise specified.





SGM4703 FUNCTIONAL BLOCK DIAGRAM





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SGM4703 APPLICATION INFORMATION

The SGM4703 is a high-power, high-efficiency, stereo Class-D audio power amplifier with adjustable power limit (APL) and automatic level control (ALC). It operates with a wide range of supply voltages from 5V to 26V. With 24V supply voltage, it can deliver $2 \times 40W$ peak output power for a pair of 8Ω speakers with 10% THD+N.

The high efficiency of SGM4703 extends battery life in playing music and allows it to deliver an output power of $2 \times 20W$ without the need for a bulky heat sink on a two-layer system board. Its high PSRR and low EMI emission reduce system design and manufacturing complexities, as well as thus lower system cost.

The SGM4703 features APL and ALC. The APL limits peak audio outputs to a user-defined value to protect audio speakers from excessive power dissipation and over-load. The APL and ALC adjust the voltage gain of the audio amplifiers in response to over-limit audio inputs, eliminating output clipping distortion while maintaining a maximally allowed dynamic range of audio outputs. The limiting voltage of APL and ALC can be either the supply voltage or a user-defined value.

The SGM4703 can be configured into driving either a pair of speakers in Bridge-Tied-Load (BTL) configuration for stereo applications or a single speaker in Parallel BTL (PBTL) configuration for mono applications. In PBTL configuration, with 15V supply voltage, it can deliver into a 3Ω speaker an output power of 33W with 1% THD+N, or an ALC output power of 30W with THD+N less than 0.5%.

The SGM4703 features two PWM modulation schemes for use in Class-D audio amplifiers: Dual-Side-Modulation (DSM) and Single-Side-Modulation (SSM), allowing for system optimization for higher efficiency or lower THD. The SGM4703 includes comprehensive protection modes against various operating faults including under-voltage, over-voltage, over-current, overtemperature, and DC-detect for safe and reliable operation.

Operating Mode Control

The SGM4703 features APL and ALC modes of operation. In APL mode, peak audio outputs are clamped (hard-limited) to a voltage level defined by the PLIMIT pin, protecting audio speakers from excessive power dissipation and over-load.

As described in Table 1, depending upon the pin voltage at PLIMIT and the pin configuration at ALC, the SGM4703 can be configured into one of four operating modes: Mute, APL, ALC, and Traditional. In SGM4703, the pin voltage at PLIMIT, V_{PLIMIT} , defines the limiting voltage of audio outputs for both APL and ALC modes.

If V_{PLIMIT} is set less than 0.3V, the device operates in mute mode regardless of the pin configuration at ALC.

If V_{PLIMIT} is set higher than 4.5V with the ALC pin unconnected, the device operates in a traditional Class-D mode without APL or ALC. In this mode, the output clipping distortion will occur as peak output voltages reach to the supply voltage PVDD.

If V_{PLIMIT} is set in the range from 0.7V to 2.5V with the ALC pin connected to ground through an external resistor of $0k\Omega$, $68k\Omega$, or $300k\Omega$, the device operates in APL mode. The audio outputs in APL mode are limited to a value approximately equal to (6 × V_{PLIMIT}).

If V_{PLIMIT} is set higher than 4.5V with the ALC pin connected to ground through an external resistor of $0k\Omega$, $68k\Omega$, or $300k\Omega$, the device operates in ALC mode and the limiting voltage of audio outputs is internally set at the supply voltage. Thus, the peak voltage of audio outputs is limited to a value that is substantially close to PVDD.

Table 1. Operatin	g Mode Control
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V _{PLIMIT}	R _{ALC}	Mode	Description
V _{PLIMIT} < 0.3V	Х	Mute	Audio outputs shorted to PGND.
$V_{PLIMIT} < 4.5V$	Open	Х	Not applicable.
$V_{PLIMIT} > 4.5V$	Open	Traditional	No APL and No ALC.
0.7V < V _{PLIMIT} < 3.5V	0kΩ, 68kΩ, 300kΩ	APL	Audio outputs limited to a value defined by V _{PLIMIT} .
$V_{PLIMIT} > 4.5V$	to GND	ALC	Audio outputs limited to the supply voltage PVDD.



Figure 4 depicts large audio outputs in different operating modes when excessive inputs are applied to cause peak outputs higher than either the supply voltage or a user-defined voltage limit lower than the supply voltage.



Figure 4. Large Audio Outputs in Different Operating Modes

GVDD Supply

The GVDD is an internally generated supply voltage for internal circuitry. It is also used as the supply voltage for the resistor divider to set the voltage at the PLIMIT pin. It is highly suggested to decouple the GVDD pin with a 1μ F ceramic capacitor to ground for stable operation. Note that the current drawn from the GVDD pin by external circuitry, including all the resistor dividers at ALC, GAIN, FREQ, and PLIMIT pins, must be kept less than 5mA.

MUTE Control

The SGM4703 can be configured into mute mode when the PLIMIT pin is pulled low by an inverting transistor, as shown in Figure 5. In mute mode, the output stages of both audio amplifiers are in Hi-Z and the differential audio outputs (VOPL/R and VONL/R) are pulled to ground through on-chip resistors respectively. To restore to its normal operation, the output of the inverting transistor is reverted to Hi-Z state, allowing the resistor divider (from GVDD to ground) tapped at the PLIMIT pin to set the voltage limit for APL.



Figure 5. Example Circuit Diagram of Mute Control

Automatic Level Control (ALC)

The automatic level control is to maintain the audio outputs for a maximum voltage swing without clip distortion when excessive inputs that may cause output clipping are applied. With ALC, the SGM4703 lowers the voltage gain of both audio amplifiers to an appropriate value such that output clipping is substantially eliminated.

In Figure 6, "Attack" is the duration where the voltage gain of the audio amplifiers decreases until output clipping is substantially eliminated. "Release" is the duration where the voltage gain of the audio amplifiers recovers (increases) until it reaches to a value that is maximally allowed without output clipping.







ALC Mode Select

The SGM4703 can be configured into ALC or Non-ALC mode via the ALC pin, as described in Table 2. When the ALC pin is left unconnected, the SGM4703 operates in Non-ALC mode. The Non-ALC mode is typically chosen for applications where maximum audio loudness is desired and the amount of output clipping distortions can be measurably controlled at the audio source. In other pin configurations, the SGM4703 operates in ALC mode with three specific audio dynamic characteristics. For most applications, the ALC mode is preferred for its capability to substantially

eliminate output clipping distortion, excessive power dissipation, and speaker over-load.

Three sets of ALC dynamic characteristics can be selected for specific sound effects, as described in Table 2. The ALC-1 mode (the ALC pin shorted to GND) plays music in a most mellow manner with negligible amount of clipping distortion and lower average output power. On the other hand, the ALC-3 mode (the ALC pin shorted to GND via a $300k\Omega$ resistor) plays music in a most dynamic manner with some extent of clipping distortion and higher average output power (loudness).

Table 2. ALC Mode Select

ALC	ALC	ALC Sound Effects		
Pin Configuration	Mode	Loudness	Output Clipping Distortion	
Open	Non-ALC	Potentially highest loudness	No control on output clipping	
Shorted to GND	ALC-1	Most mellow sound (Lowest loudness under ALC)	Negligible output clipping	
68kΩ to GND	ALC-2	Medium loudness	Slight output clipping	
300kΩ to GND ALC-3 Most dynamic sound (Highest loudness under ALC) Acceptable output clipping				
Note: The resistor tolerance of R _{ALC} should be 5% or better.				

Voltage Gain Setting

To accommodate various application requirements, the SGM4703 features four selectable voltage gains for audio amplifiers. An external resistor R_{GAIN} from the GAIN pin to ground sets the voltage gain, as shown in Table 3.

GAIN Pin Configuration	R _{iNi} (kΩ)	A _V (V/V)	A _V (dB)	
Open	30	20	26	
Shorted to GND	20	30	30	
68kΩ to GND	12	50	34	
300kΩ to GND	60	10	20	
Note: The resistor tolerance of R _{GAIN} should be 5% or better.				

Table 3. Voltage Gain Select

Although the voltage gains as described in Table 3 vary a little (less than 2%) from parts to parts, the input impedances at the same voltage gain may vary by $\pm 20\%$ over parts, due to process variations in the actual resistance of the input resistors. For design purposes, the input impedance should be assumed to be $10k\Omega$, which is the absolute minimum input impedance of the audio amplifiers in SGM4703. At lower gain settings, the input impedance could be as high as $60k\Omega$. The voltage gain of the audio amplifiers can be slightly adjusted by inserting small external input resistors R_{INE} , in series with the input capacitors C_{IN} , as depicted in Figure 7 and Figure 8 for differential and single-ended inputs respectively. In the figures, it is required that $C_{IN} = C_{INL1/2} = C_{INR1/2}$ and $R_{INE} = R_{INL1/2} = R_{INR1/2}$.

As depicted in Figure 8, the unused inputs of SGM4703 in single-ended inputs applications must be AC-grounded at the audio source. Also, take care to match the impedances of the two differential inputs.



Figure 7. Gain Setting (Differential Inputs)



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Figure 8. Gain Setting (Single-Ended Inputs)

The value of R_{INE} (in $k\Omega$) for a given voltage gain can be calculated by Equation 1, where A_V is the voltage gain of the audio amplifier.

$$A_{\rm V} = \frac{600}{R_{\rm INE} + R_{\rm INI}} \tag{1}$$

The choice of the voltage gain will strongly influence the loudness and quality of audio sounds. In general, the higher the voltage gain is, the louder the sound is perceived. However an excessive voltage gain may cause audio outputs to be severely clipped (Non-ALC mode) or compressed (ALC mode) for high-level (loud) audio sounds. On the other hand, an unusually low gain may cause relatively low-level (quite) sounds soft or inaudible. Thus it is crucial to choose a proper voltage gain for well balanced audio quality.

The voltage gain is chosen based upon various system-level considerations including the supply voltage, the dynamic range of audio sources and speaker loads, and the desired sound effects. As a general guideline, the voltage gain can be simply expressed in Equation 2. In the equation, $V_{\text{IN, MAX}}$ (in V_{RMS}) is the maximum input level from the audio source, PVDD (in volts) is the supply voltage, and α is the design parameter, which ranges from 0.66 to 1.0. The higher α is, the higher the average output power (louder) is, with some degree of compression for high-level audio sounds.

$$A_{V} = \frac{\alpha \times PVDD}{V_{IN,MAX}}$$
(2)

As an example, Table 4 shows the voltage gain for various input levels with PVDD at 12V and 18V and α at about 0.80. In the table, R_{INE} is the external input resistor in series with the input capacitor and R_{INI} is the internal input resistor.

Table 4. Typical Voltage Gain Settings for Various V_{DD} & Audio Input Levels

V _{IN, MAX} (V _{RMS})	A _v (V/V)	A _v (dB)	R _{GAIN} to GND (kΩ)	R _{iNi} (kΩ)	R _{INE} (kΩ)
V _{DD} = 12	V				
0.5	20	26	Open	30	0
0.7	13.3	22.5	Open	30	15
1.0	10	20	300	60	0
V _{DD} = 18	V				
0.5	30	29.5	0	20	0
0.7	20	26	Open	30	0
1.0	15	23.5	Open	30	10
V _{DD} = 24	V _{DD} = 24V				
0.5	40	32	68	12	3.0
0.7	28.5	29	0	20	1.0
1.0	20	26	Open	30	0

PWM Frequency Setting

To accommodate various application requirements, the SGM4703 features two selectable PWM frequencies with optional spread-spectrum for the Class-D audio amplifiers. An external resistor R_{FREQ} from the FREQ pin to ground sets the PWM frequency and optional spread-spectrum, as shown in Table 5.

Table 5. PWM Frequency Select with Optional Spread-Spectrum

FREQ Pin Configuration	PWM Frequency (kHz)	Spread-Spectrum		
Open	360	No		
Shorted to GND	360	Yes		
68kΩ to GND	500	No		
300kΩ to GND	500	Yes		
Note: The register tolerance of Pshould be 5% or botton				

Note: The resistor tolerance of R_{FREQ} should be 5% or better.

PWM Modulation Scheme

To accommodate various application requirements, the SGM4703 features two PWM modulation schemes, i.e., Single-Side-Modulation (SSM) and Double-Side-Modulation (DSM). In typical applications, the SSM scheme is preferred for its lower EMI and higher PSRR and efficiency. The modulation scheme is selected via the MODS pin, as described in Table 6. The PWM modulation scheme is latched during power-up and cannot be changed while the device is in operation.

Table 6. Modulation Scheme Select

MODS	Modulation Scheme
High or Open	SSM
Low	DSM



Double-Side-Modulation (DSM)

With DSM scheme, during an idle condition (no audio signal applied), both VOPL/R and VONL/R outputs are at 50% duty cycle and in phase with each other, resulting in little or no current flowing through the speaker. When a positive audio input is applied, the duty cycle of VOPL/R is greater than 50% and VONL/R is less than 50%, resulting in a positive current flowing through the speaker. When a negative audio input is applied, the duty cycle of VOPL/R is less than 50%, resulting in a negative audio input is applied, the duty cycle of VOPL/R is less than 50% and VONL/R is greater than 50%, resulting in a negative current flowing through the speaker. Compared with the traditional modulation scheme, the DSM scheme reduces the switching current, which minimizes any I²R losses in the speaker load and eliminates the need for an LC output filter for most applications.

Single-Side-Modulation (SSM)

The SSM scheme alters the DSM scheme in order to achieve higher efficiency with a slight penalty in THD degradation and more attention required for the selection of the output filter. With SSM scheme, the audio outputs operate with less than 10% modulation during an idle condition. When an audio signal is applied, one output will decrease and another one will increase. The decreasing output signal will quickly rail to ground at which point all the audio modulation takes place through the rising output. The result is that only one output is switching during a majority of the audio cycle. Efficiency is improved with SSM scheme due to the reduction of switching losses. The THD penalty with SSM scheme is minimized by the on-chip linear feedback loop.

Volume Fade-In and Fade-Out

The SGM4703 features volume fade-in and fade-out to reduce intermittent sound and eliminate uncomfortable hearing experience during the transitions when the device enters or exits the normal operation. Figure 9 and Figure 10 show the audio output waveforms during fade-in and fade-out respectively.







PBTL Configuration (Mono Mode)

The SGM4703 features an optional mono mode that allows the left and right channels to operate in parallel BTL configuration. To operate the SGM4703 in mono mode, connect the INNR and INPR pins (pin 11 and 12) directly to ground (no decoupling capacitors). In mono mode, as shown in Figure 11, an audio input signal applied to the left channel (pin 3 and 4) is routed to the H-bridge of both channels. Note that the mono mode is intended to be configured strictly by the hardware connection. Leaving either INNR or INPR pin unconnected while the audio outputs VOPL/R and VONL/R are wired together in PBTL configuration can trigger an over-current or thermal overload protection or both. The mono mode is configured by the following arrangement:



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- Connect INPR and INNR pins directly to ground (no decoupling capacitors).
- Connect VOPL to VONL together as one terminal of the speaker and connect VOPR to VONR together as the other terminal of the speaker. Use heavy PCB traces as close as possible to the device.
- Place the speaker between the left and right-channel outputs.
- Apply an audio signal to the left-channel inputs (INPL and INNL pins).



Figure 11. PBTL Configuration for Mono Applications

Click-and-Pop Suppression

The SGM4703 features comprehensive click-and-pop suppression. During startup, the click-and-pop suppression circuitry reduces any audible transients internal to the device. When entering into shutdown, the differential audio outputs VOPL/R and VONL/R ramp down to ground quickly and simultaneously.

PSRR Enhancement

Without a dedicated pin for the common-mode voltage bias and an external holding capacitor onto the pin, the SGM4703 achieves a PSRR, 80dB at 1kHz with SSM scheme.

Startup and Shutdown

The SGM4703 requires a power-up sequence (see Figure 12). Please hold EN low at least 10ms after PVDD and AVDD supply voltages are turned on.

The SGM4703 employs the EN pin to minimize power consumption when not in use. When the EN pin is pulled low, the SGM4703 is forced into shutdown mode. At this time, all the analog circuitry is de-biased and the supply current is reduced to less than 60µA, and the differential outputs are shorted to ground through an on-chip resistor (5k Ω) individually. Once in shutdown mode, the EN pin must remain low for at least 10ms (t_{SD}) for the shutdown settling time before it can be pulled high again. When the EN pin is asserted high, the device exits out of shutdown mode and enters into normal operation after the startup time (t_{STUP}) of 45ms.

An on-chip pull-down resistor of $250k\Omega$ is included onto the EN pin. Thus, shutdown mode is the state when the power supply is first applied to the device. Whenever possible, please hold the EN pin low until the device is properly powered up and the audio signals at the inputs are stable. Also, for best power-off pop performance, place the device in shutdown mode prior to removing the power supply voltage.

Note that the setting at the MODS pin is latched during startup and cannot be changed while the device is in operation. To change the setting of the MODS pin, the device must be first brought into shutdown mode by pulling the EN pin low for at least 10ms before it can be restored to its normal operation.





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Protection Modes

For safe operation, the SGM4703 incorporates comprehensive protection circuits against various operating faults including Under-Voltage, Over-Voltage, Over-Current, Over-Temperature, and DC-Detect, as described in Table 7. In the shutdown mode, all the analog circuitry is de-biased with differential outputs to be shorted to ground. In the mute mode, all the analog circuitry is enabled with differential outputs to be shorted to ground.

Under-Voltage Lockout (UVLO)

The SGM4703 incorporates circuitry to detect a low supply voltage for safe and reliable operation. When the supply voltage is first applied, the SGM4703 will remain inactive until the supply voltage exceeds 4.6V (V_{UVLOUP}). When the supply voltage is removed and drops below 4.3V (V_{UVLODN}), the SGM4703 enters into mute mode, where the differential audio outputs VOPL/R and VONL/R are pulled to ground through on-chip resistors (5k Ω) individually.

Over-Voltage Protection (OVP)

The SGM4703 features over-voltage protection. When the supply voltage exceeds 28V (V_{VOPUP}), the device enters into mute mode, where the differential audio outputs VOPL/R and VONL/R are pulled to ground through on-chip resistors (5k Ω) individually. The device will resume normal operation once the supply voltage returns to a value lower than 26.5V (V_{VOPDN}).

Over-Temperature Shutdown (OTSD)

When the die temperature exceeds 160°C, the device enters into mute mode, where the differential audio outputs VOPL/R and VONL/R are pulled to ground through on-chip resistors (5k Ω) individually. The device will resume normal operation once the die temperature returns to a lower temperature, which is about 20°C lower than the threshold.

Over-Current Protection (OCP)

In operation, the outputs of Class-D amplifiers are constantly monitors for any over-current and/or short-circuit conditions. When a short-circuit condition between two differential outputs, differential outputs to PVDD or ground is detected and the output stages of the amplifiers are immediately forced into high impedance state. If the fault persists over a prescribed period, the fault condition is latched and reported on the FAULTB pin as a low state. Also, the SGM4703 enters into shutdown mode and remains in shutdown mode. The latch can be cleared by cycling the EN pin through the low state.

If automatic recovery from the OCP fault is desired, connect the FAULTZ pin directly to the EN pin, as shown in Figure 13. It allows the FAULTZ pin to automatically drive the EN pin low, which clears the OCP latch.

DC-Detect Protection (DCP)

The SGM4703 features DCP circuit to protect the speakers from large DC current. A DC-detect fault is issued when the duty cycle of differential outputs of either channel exceeds 20% for more than 720ms at the same polarity. Note that the DCP threshold is a function of the supply voltage, as shown in Table 8. To avoid nuisance faults due to the DCP circuit, it is recommended to hold the EN pin low during startup until the audio signals at the inputs are stable. Also, take care to closely match the impedance seen at two differential inputs.

A DC-detect fault is latched and reported on the FAULTB pin as a low state. Also, the SGM4703 enters into shutdown mode and remains in shutdown mode. The latch can be cleared by cycling the EN pin through the low state.

Fault	Detection Condition	FAULTB	Audio Outputs	Mode	Latched or Self-Recovery
Over-Current	Audio outputs shorted to PVDD or GND or each other	Low	$5k\Omega$ to GND	Shutdown	Latched
DC-Detect	See Table 8	Low	$5k\Omega$ to GND	Shutdown	Latched
Over-Temperature	T _J > 160°C	-	5kΩ to GND	Mute	Self-Recovery
Under-Voltage	PVDD < 4.3V	-	5kΩ to GND	Mute	Self-Recovery
Over-Voltage	PVDD > 28V	-	5kΩ to GND	Mute	Self-Recovery

Table 7. Protection Modes of Various Operating faults

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SGM4703 APPLICATION INFORMATION (continued)

Table 8	DC-Detect	Threshold	Voltages
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PVDD (V)	V _{os} , Output Offset Voltage (V)
6.5	1.3
12	2.4
15	3.0
18	3.6

If automatic recovery from the DCP fault is desired, connect the FAULTB pin directly to the EN pin, as shown in Figure 13. It allows the FAULTB pin to automatically drive the EN pin low, which clears the DCP latch.



Figure 13. Automatic Recovery from OCP or DCP Fault Latch

Class-D Audio Amplifier

The audio power amplifiers in SGM4703 operate in much the same way as traditional Class-D amplifiers and similarly offer much higher power efficiency.

Fully Differential Amplifier

The SGM4703 includes a pair of fully differential amplifiers with differential inputs and outputs. The fully differential amplifiers ensure that the differential output voltages are equal to the differential input voltages times the amplifier gain. Although the SGM4703 supports for a single-ended input, differential inputs are much preferred for applications where the environment can be noisy in order to ensure maximum SNR.

Low-Emi Filterless Output Stage

Traditional Class-D audio amplifiers require for the use of external LC filters, or shielding, to meet EN55022B electromagnetic-interference (EMI) regulation standards. The SGM4703 applies an edge-rate control circuitry to reduce EMI emissions, while maintaining high power efficiency.

Filterless Design

The SGM4703 does not require an output filter. The device relies on the inherent inductance of the speaker coil and the natural filtering of both the speaker and the human ear to recover the audio component of the

square-wave output. By eliminating the output filter, a smaller, less costly, and more efficient solution can be accomplished.

Because the frequency of the audio outputs is well beyond the bandwidth of most speakers, voice coil movement due to the square-wave frequency is very small. Although this movement is small, a speaker not designed to handle the additional power can be damaged. For optimum performance, use speakers with series inductances greater than 10μ H. Typical 4Ω speakers exhibit series inductances from 10μ H to 47μ H.

Ferrite Bead Output Filter

With an edge-rate control circuitry in SGM4703, it is possible to design a low EMI, highly efficient class-D audio amplifier without the need for classic LC reconstruction filters when the amplifier drives speaker loads with short speaker wires (less than 10cm). However, EMI suppression can be further reduced by use of a low-cost ferrite bead filter comprising a ferrite bead and a capacitor, as shown in Figure 14. The ferrite bead filter is applied to block radiation in the range of 30MHz and above from appearing on the speaker wires and the power supply lines. The impedance of the ferrite bead is used with a small capacitor in the range of 1nF to reduce the frequency spectrum of the signal to an acceptable level. For best performance, the resonant frequency of the ferrite bead filter should be less than 10MHz.

Choose a ferrite bead with low DC resistance (DCR) and high impedance $(100\Omega \sim 330\Omega)$ at high frequencies (>100MHz). The current flowing through the ferrite bead must be also taken into consideration. The effectiveness of ferrites can be greatly aggravated at much lower than their rated current values. Choose a ferrite bead with a rated current no less than 4A for 8 Ω loads, 7A for 4 Ω loads, and 9A for 3 Ω loads (in PBTL configuration).

A high quality ceramic capacitor is needed for the ferrite bead filter. A low ESR ceramic capacitor with good temperature and voltage characteristics will be the best choice. The capacitor value varies based on the ferrite bead chosen and the actual speaker lead length. It is crucial to place each ferrite bead filter tightly together and individually close to VOPL/R and VONL/R pins respectively.





Figure 14. Ferrite Bead Filter for EMI Reduction

Additional EMI improvements may be obtained by adding snubber networks from each of the class-D outputs to ground. Suggested values for a simple RC series snubber network are 10Ω in series with a 680pF capacitor. Note that design of the RC snubber circuit is specific to every application and must take into account the parasitic reactance of the system board to reach proper values of R and C. Evaluate and ensure that the voltage spikes (overshoots and undershoots) at VOPL/R and VONL/R on the actual system board are within their absolute maximum ratings. Pay close attention to the layout of the RC snubber circuit to be tight and individually close to VOPL/R and VONL/R pins, respectively.

LC Output Filter

For applications with nearby highly noise sensitive circuits or long speaker wires, it may become necessary to add an LC reconstruction filter for best EMI reduction. A classic second-order lowpass filter, as shown in Figure 15, can be used for the output filter.

VOP L_1 C_1 C_2 LSL L_2 C_3 C_3

Figure 15. LC Output Filter for EMI Reduction

In Figure 15, the corner frequency of the LC lowpass filter, as given by Equation 3, must be designed to be sufficiently high to allow for high-frequency components of audio signals, yet be low enough to sufficiently attenuate high-frequency components of the audio outputs from VOPL/R and VONL/R. The corner frequency of the filter is typically set about 50kHz. In Equation 3, it is assumed that $L = L_1 = L_2$, $C_G = C_2 = C_3$, and $C = 2 \times C_1 + C_G$.

$$f_{C, LPF} = \frac{1}{2\pi\sqrt{LC}}$$
(3)

The quality factor Q of the output filter is important. Lower Q increases output noise and higher Q results in passband peaking at frequencies near the corner frequency. The quality factor of the filter is typically set between 0.5 and 0.8. As shown in Equation 4, the speak load, R_{LOAD} , affects the quality factor of the filter.

$$Q = \frac{R_{LOAD}}{2} \times \sqrt{\frac{C}{L}}$$
(4)

Table 9 lists suggested component values of L₁, L₂, C₁, C₂, and C₃ for the second-order Butterworth lowpass filter with the speaker load at 2Ω , 3Ω , 4Ω , or 8Ω .

Speaker Load (Ω)	Modulation Scheme	L ₁ , L ₂ (µH)	C ₁ (μF)	C ₂ , C ₃ (μF)	f _{C, LPF} (kHz)	Q
8	SSM	15	0.22	0.1	56	0.76
	DSM	15	-	0.56	55	0.77
4	SSM	10	0.47	0.15	48	0.68
4	DSM	10	-	1.0	50	0.63
2	SSM	8.2	0.47	0.22	52	0.56
3	DSM	8.2	-	1.2	51	0.57
2	SSM	5.6	0.68	0.22	54	0.53
2	DSM	5.6	-	1.5	55	0.52

Table 9. Suggested Component Values of LC Output Filter



Audio Input Capacitors (C_{INL1} , C_{INL2} , C_{INR1} , C_{INR2})

The input DC decoupling capacitors are recommended to bias the incoming audio inputs to a proper DC level. The input capacitor C_{IN} , in conjunction with the amplifier input resistance (including both internal resistor R_{INI} and external resistor R_{INE} , if any) forms a highpass filter that removes the DC bias of the audio inputs. The corner frequency $f_{C, HPF}$ of the highpass filter is given by Equation 5. In the equation, it is assumed that $R_{INE} = R_{INL1} = R_{INL2} = R_{INR1} = R_{INR2}$ and $C_{IN} = C_{INL1} = C_{INL2} = C_{INR1} = C_{INR2}$.

$$f_{C, HPF} = \frac{1}{2\pi \times (R_{INE} + R_{INI}) \times C_{IN}}$$
(5)

 R_{INE} is the external input resistance for a specific voltage gain. Note that the variation of the actual input resistance will affect the voltage gain proportionally. Choose R_{INE} with a tolerance of 2% or better.

Choose C_{IN} such that $f_{C, HPF}$ is well below the lowest frequency of interest. Setting it too high affects the amplifiers' low-frequency response. Consider an example where the specification calls for $A_V = 26dB$ and $f_{C, HPF} = 5Hz$. In this example, $R_{INE} = 0\Omega$ and $R_{INI} = 30k\Omega$ and C_{IN} is calculated to be about 1.06μ F; thus 1μ F, as a common choice of capacitance, can be chosen for C_{IN} .

Any mismatch in capacitance between two audio inputs will cause a mismatch in the corner frequencies. Severe mismatch may also cause turn-on pop noise, PSRR, CMRR performance. Choose C_{IN} with a tolerance of ±2% or better.

Furthermore, the type of the input capacitor is crucial to audio quality. For best audio quality, use capacitors whose dielectrics have low-voltage coefficients, such as tantalum or aluminum electrolytic. Capacitors with high-voltage coefficients, such as ceramics, may result in increased distortion at low frequencies.

Supply Coupling Capacitors (C_{PVDD} , C_{AVDD} , C_{GVDD} , C_{PLIMIT})

Decouple each pair of PVDD pins respectively with a 1μ F low-ESR ceramic capacitor (X7R or X5R) to GND. It is highly suggested to add an additional 0.01μ F ceramic capacitor, in tandem with each 1μ F capacitor, for high-frequency decoupling. The rated voltage of the supply coupling capacitors must be higher than the power supply voltage with sufficient tolerance to limit the effects of DC bias. Place the decoupling capacitors as individually close as possible to each pair of PVDD pins.

If the power supply input is located more than a few inches from SGM4703, additional bulk supply decoupling capacitors (electrolytic or tantalum type) may be required. Add a large (220μ F or greater) bulk capacitor on the PVDD power bus in close proximity to the SGM4703.

Decouple the AVDD pin with a 1µF low-ESR ceramic capacitor to AGND. Place the decoupling capacitor as close as possible to the AVDD pin. Furthermore, add a small decoupling resistor (R_{AVDD}) of 10 Ω between the system power supply and the AVDD pin, preventing high-frequency transients of PVDD from interfering with on-chip linear amplifiers.

Decouple the GVDD pin with a 1μ F low-ESR ceramic capacitor to AGND. Place the decoupling capacitor close to the GVDD pin.

Decouple the PLIMIT pin with a 0.1μ F low-ESR ceramic capacitor to AGND for high-frequency filtering. Place the decoupling capacitor close to the PLIMIT pin.

Printed Circuit Board (PCB) Layout

As a high power, high efficiency, Class-D stereo audio power amplifier, the SGM4703 requires proper PCB layout and grounding to ensure high efficiency, low distortion, and low EMI emission. Use wide traces for the power supply inputs (PVDD) and audio outputs (VOPL/R and VONL/R) to minimize losses due to parasitic trace resistances. Route all traces that carry switching transients away from the traces or components in the audio signal path.

Ground Plane – It is required to use a solid metal plane with sufficiently wide area as a central ground GND for SGM4703. All the power ground pins PGND are directly shorted to the large ground plane GND, which serves as a central "star" ground for the SGM4703. Use a single point of connection between the analog ground AGND and the ground plane GND to minimize the coupling of high-current switching noise onto audio signals.



Output Filters – Place each audio output filter (ferrite bead or LC filter) individually close to their respective output pins, VOPL/R and VONL/R, for best EMI performance and operational robustness. Keep the current loop from each of the audio outputs through the output filters and back to the PGND pins as short and tight as possible.

Power Dissipation – The maximum output power of SGM4703 can be severely limited by its thermal dissipation capability. To ensure the device operating properly and reliably at maximum output power without incurring over-temperature shutdown, the following guidelines are given for best thermal dissipation capability:

- Fill both top and bottom layers of the system board with solid GND metal traces.
- Solder the thermal pad directly onto a grounded metal plane.
- Place lots of equally-spaced vias underneath the thermal pad connecting the top and bottom layers of GND. The vias are connected to a solid metal plane on the bottom layer of the board.
- Reserve wide and uninterrupted areas along the thermal flow on the top layer, i.e., no wires cutting through the GND layer and obstructing the thermal flow.
- Avoid using vias for traces carrying high current.



SGM4703 TYPICAL APPLICATION CIRCUITS



Figure 16. Differential Inputs in Non-ALC Mode with DSM





SGM4703 TYPICAL APPLICATION CIRCUITS (continued)



Figure 18. Single-Ended Inputs in APL Mode with Mute Control



Figure 19. Differential Inputs in ALC-2 Mode with DSM in PBTL Configuration



SGM4703 PACKAGE OUTLINE DIMENSIONS

TSSOP-28 (Exposed Pad)





RECOMMENDED LAND PATTERN (Unit: mm)





	Symbol	Dimer In Milli	nsions meters	Dimensions In Inches			
Ζ		MIN	MAX	MIN	MAX		
	A		1.200		0.047		
	A1	0.050	0.150	0.002	0.006		
	A2	0.800	1.050	0.031	0.041		
	b	0.190	0.300	0.007	0.012		
	с	0.090	0.200	0.004	0.008		
	D	9.600	9.800	0.378	0.386		
	D1	5.300	5.700	0.209	0.224		
	Е	4.300	4.500	0.169	0.177		
	E1	2.400	2.800	0.094	0.110		
	E2	6.200	6.600	0.244	0.260		
	е	0.650) BSC	0.026 BSC			
	L	1.000) BSC	0.039 BSC			
	L1	0.450	0.750	0.018	0.030		
	θ	0°	8°	0°	8°		

NOTES:

1. Body dimensions do not include mode flash or protrusion.

2. This drawing is subject to change without notice.



SGM4703 TAPE AND REEL INFORMATION

REEL DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TSSOP-28 (Exposed Pad)	13″	17.6	6.80	10.20	1.60	4.0	8.0	2.0	16.0	Q1



深圳市矽源特科技有限公司 ShenZhen ChipSourceTek Technology Co.,Ltd.

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
13″	386	280	370	5	DD0002